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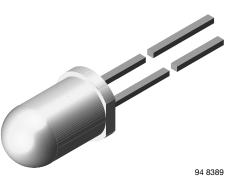


www.vishay.com

TSHF6210

Vishay Semiconductors

High Speed Infrared Emitting Diode, 890 nm, Surface Emitter Technology



94 8389

DESCRIPTION

TSHF6210 is an infrared, 890 nm emitting diode based on surface emitter chip technology with high radiant power and high speed, molded in a clear, untinted plastic package.

FEATURES

- Package type: leaded
- Package form: T-1¾
- Dimensions (in mm): Ø 5
- Peak wavelength: λ_p = 890 nm
- High reliability
- High radiant power
- · High radiant intensity
- Angle of half intensity: $\varphi = \pm 8^{\circ}$
- Low forward voltage
- Suitable for high pulse current operation
- Good spectral matching with Si photodetectors
- · Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

APPLICATIONS

- · Infrared high speed remote control and free air data transmission systems with high modulation frequencies or high data transmission rate requirements
- · Transmission systems according to IrDA requirements and for carrier frequency based systems (e.g. ASK/FSK coded, 450 kHz or 1.3 MHz)

PRODUCT SUMMARY				
COMPONENT	l _e (mW/sr)	φ (°)	λ _P (nm)	t _r (ns)
TSHF6210	327	± 8	890	10

Note

Test conditions see table "Basic Characteristics"

ORDERING INFORMATION					
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM		
TSHF6210	Bulk	MOQ: 4000 pcs, 4000 pcs/bulk	T-1¾		

Note

MOQ: minimum order quantity

ABSOLUTE MAXIMUM RATINGS ($T_{amb} = 25 \text{ °C}$, unless otherwise specified)				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Reverse voltage		V _R	5	V
Forward current		١ _F	100	mA
Peak forward current	$t_p/T = 0.5, t_p = 100 \ \mu s$	I _{FM}	200	mA
Surge forward current	t _p = 100 μs	I _{FSM}	1	А
Power dissipation		Pv	170	mW
Junction temperature		Тj	100	°C
Ambient temperature range		T _{amb}	-40 to +85	°C
Storage temperature range		T _{stg}	-40 to +100	°C
Soldering temperature	$t \le 5$ s, 2 mm from case	T _{sd}	260	°C
Thermal resistance junction to ambient	J-STD-051, leads 7 mm soldered on PCB	R _{thJA}	230	K/W

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1 For technical questions, contact: emittertechsupport@vishay.com Document Number: 81734

RoHS

COMPLIANT HALOGEN FREE GREEN (5-2008)

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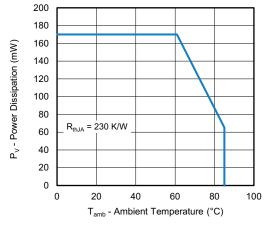


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

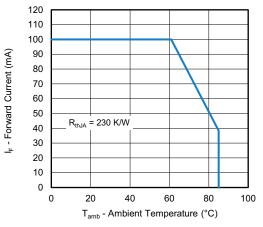


Fig. 2 - Forward Current Limit vs. Ambient Temperature

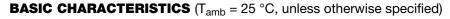
BASIC CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Forward voltage	I _F = 100 mA, t _p = 20 ms	V _F	-	1.5	1.7	V
	I _F = 1 A, t _p = 100 μs	V _F	-	3	-	V
Temperature coefficient of V_F	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	TK _{VF}	-	-1.3	-	mV/K
Reverse current		I _R	Not designed for reverse operation			μA
Junction capacitance	$V_{\rm R}$ = 0 V, f = 1 MHz, E = 0 mW/cm ²	Cj	-	55	-	pF
Radiant intensity	I _F = 100 mA, t _p = 20 ms	l _e	150	327	450	mW/sr
	I _F = 1 A, t _p = 100 μs	l _e	-	2700	-	mW/sr
Radiant power	I _F = 100 mA, t _p = 20 ms	фе	-	53	-	mW
Temperature coefficient of ϕ_{e}	I _F = 100 mA	TKφe	-	-0.3	-	%/K
Angle of half intensity		φ	-	± 8	-	o
Peak wavelength	I _F = 100 mA	λρ	-	890	-	nm
Spectral bandwidth	I _F = 100 mA	Δλ	-	40	-	nm
Temperature coefficient of λ_p	I _F = 100 mA	ΤΚλ _ρ	-	0.3	-	nm/K
Rise time	I _F = 100 mA	t _r	-	10	-	ns
Fall time	I _F = 100 mA	t _f	-	10	-	ns

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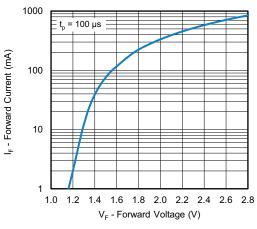


Fig. 3 - Forward Current vs. Forward Voltage

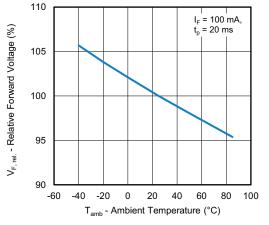


Fig. 4 - Relative Forward Voltage vs Ambient Temperature

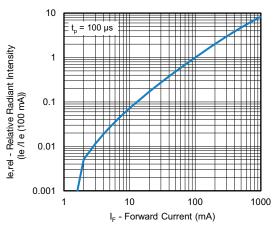


Fig. 5 - Relative Radiant Intensity vs. Forward Current

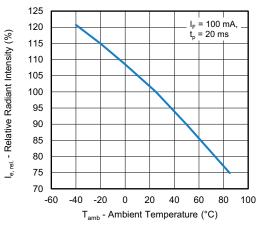


Fig. 6 - Relative Radiant Intensity vs. Ambient Temperature

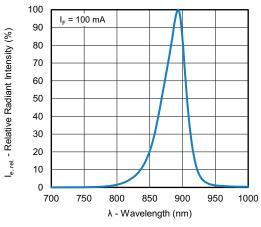
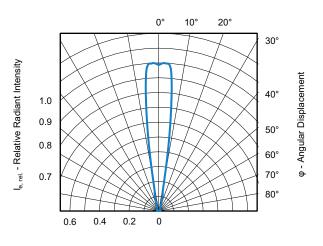


Fig. 7 - Relative Radiant Intensity vs. Wavelength





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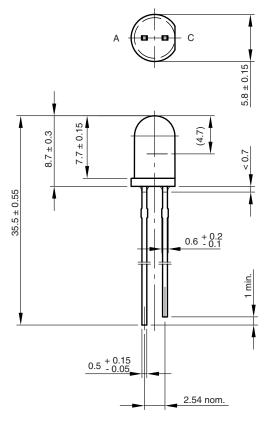


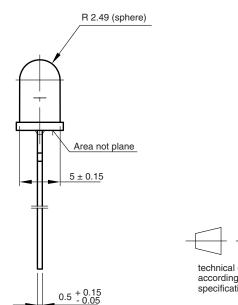
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PACKAGE DIMENSIONS in millimeters







technical drawings according to DIN specifications

6.544-5259.02-4 Issue: 8; 19.05.09 95 10917



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